

# PT85QWx45

# **Pulse Power Thyristor Switch**

Replaces DS5334-2 DS5334-3 March 2023 (LN42490)

#### **FEATURES**

- Double Side Cooling
- Fast Turn-on
- Low Turn-on Losses

#### **APPLICATIONS**

- Pulse Power
- Crowbars
- Ignitron Replacement

#### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages VDRM and VRRM (V)	Conditions
PT85QWx45	4500/16	T <sub>vj</sub> = 0°C to 125°C, IDRM = IRRM = 250mA, VDRM, VRRM t <sub>P</sub> = 10ms

Lower voltage grades available.

#### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

### PT85QWx45

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

See "additional ordering information" on page 5 regarding lead length (x).

#### **KEY PARAMETERS**

VDRM 4500V Iτ(AV) 1670A Iτsм 37000A dI/dt 22000A/μs

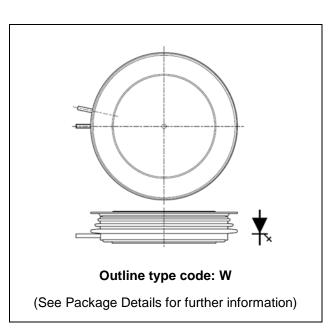


Fig. 1 Package outline

www.dynexsemi.com 1/7

## **CURRENT RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
IT(AV)	Mean on-state current	Half wave resistive load, Tcase = 80°C	1670	Α
IT(RMS)	RMS value	-	2622	Α

# **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, Tcase = 125°C	29.6	kA
l²t	I <sup>2</sup> t for fusing	Vr = 50% Vrrm	4.38	MA <sup>2</sup> s
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	37.0	kA
l²t	I2t for fusing	V <sub>R</sub> = 0	6.85	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
Rth(j-c)	Thermal resistance - junction to case	Double side cooled	DC	-	10.0	°C/kW
Rth(c-h)	Thermal resistance - case to heatsink	Clamping force 36kN	Double side	-	1.0	°C/kW
-	Violentia di controlo di contr	Blocking VDRM / VRRM		-	125	°C
Tvj Virtual junction temperature		On-state (conducting)		-	135	°C
Tstg	Storage temperature range		-55	125	°C	
Fm	Clamping force			36	44	kN

www.dynexsemi.com 2/7

# **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditions		Min.	Max.	Units
IRRM/IDRM	Peak reverse and off-state current	At VRRM/VDRM, Tcase = 125°C		-	250	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% VDRM, Tj = 125°C, Rgk $\leq$ 1.5 $\Omega$		-	200	V/µs
dl/dt	Rate of rise of on-state current	From 67% VDRM to 20kA Gate source 30A tr < 1.5µs, Tj = 125°C	Non-repetitive	-	22	kA/μs
<b>V</b> т(то)	Threshold voltage	Tvj = 125°C		-	1.45	V
ľτ	On-state slope resistance - low level	Tcase = 125°C		-	0.3	mΩ

## **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Min.	Max.	Units
<b>V</b> GT	Gate trigger voltage	VD = 24V, IT = 100A, Tvj = 25°C	-	1.5	V
Іст	Gate trigger current	VD = 24V, II = 100A, IVJ = 25 C	1.0	4.0	А

www.dynexsemi.com 3/7

# **CURVES**

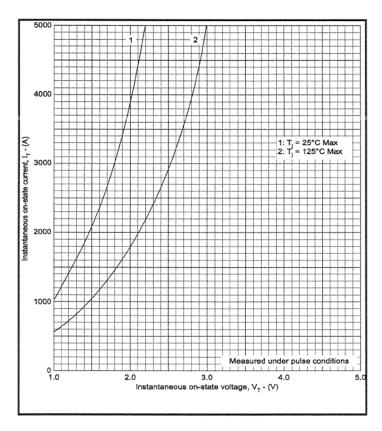


Fig. 2 Maximum (limit) on-state characteristics

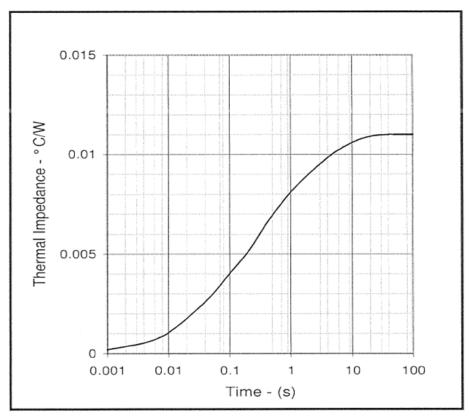


Fig.3 Maximum (limit) transient thermal impedance - double side cooled

www.dynexsemi.com 4/7

## **ADDITIONAL ORDERING INFORMATION**

PT Pulse Power Thyristor

85Q Device type

W Package outline type codex Lead length (see table, right)

45 Voltage x100

Lead length (x)				
О	No lead			
С	8"	200mm		
D	10"	250mm		
E	12"	300mm		
F	16"	400mm		
G	18"	450mm		
Н	20"	500mm		
J	24"	600mm		
K	30"	750mm		
L	40"	1000mm		

www.dynexsemi.com 5/7

### **PACKAGE DETAILS**

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE

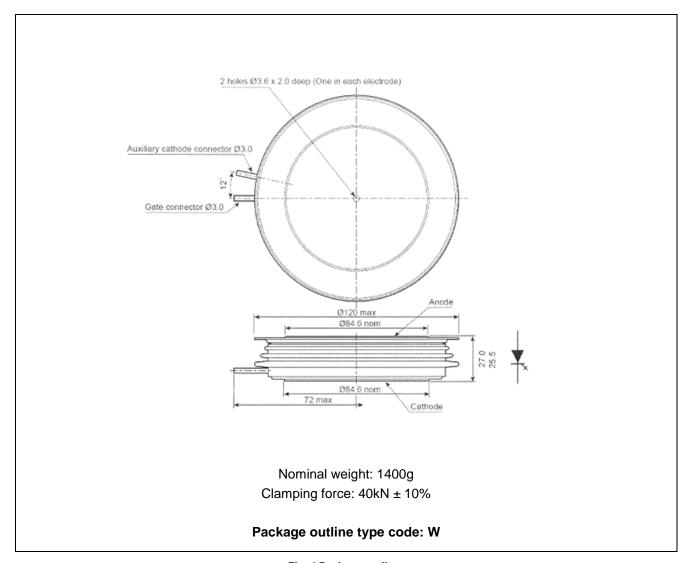


Fig. 4 Package outline

www.dynexsemi.com 6/7

#### IMPORTANT INFORMATION:

This publication is provided for information only and not for resale.

The products and information in this publication are intended for use by appropriately trained technical personnel.

Due to the diversity of product applications, the information contained herein is provided as a general guide only and does not constitute any guarantee of suitability for use in a specific application. The user must evaluate the suitability of the product and the completeness of the product data for the application. The user is responsible for product selection and ensuring all safety and any warning requirements are met. Should additional product information be needed please contact Customer Service.

Although we have endeavoured to carefully compile the information in this publication it may contain inaccuracies or typographical errors. The information is provided without any warranty or guarantee of any kind.

This publication is an uncontrolled document and is subject to change without notice. When referring to it please ensure that it is the most up to date version and has not been superseded.

The products are not intended for use in applications where a failure or malfunction may cause loss of life, injury or damage to property. The user must ensure that appropriate safety precautions are taken to prevent or mitigate the consequences of a product failure or malfunction.

The products must not be touched when operating because there is a danger of electrocution or severe burning. Always use protective safety equipment such as appropriate shields for the product and wear safety glasses. Even when disconnected any electric charge remaining in the product must be discharged and allowed to cool before safe handling using protective gloves.

Extended exposure to conditions outside the product ratings may affect reliability leading to premature product failure. Use outside the product ratings is likely to cause permanent damage to the product. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture, a large current to flow or high voltage arcing, resulting in fire or explosion. Appropriate application design and safety precautions should always be followed to protect persons and property.

#### **Product Status & Product Ordering:**

We annotate datasheets in the top right hand corner of the front page, to indicate product status if it is not yet fully approved for production. The annotations are as follows:

**Target Information:** This is the most tentative form of information and represents a very preliminary specification.

No actual design work on the product has been started.

Provisional Information: Some initial development work has been performed. The datasheet represents a view of the

end product based on very limited information. Certain details will change.

**Preliminary Information:** The product design is complete and final characterisation for volume production is in progress.

The datasheet represents the product as it is now understood but details may change.

No Annotation: The product has been approved for production and unless otherwise notified by Dynex any

product ordered will be supplied to the current version of the data sheet prevailing at the

time of our order acknowledgement.

All products and materials are sold and services provided subject to Dynex's conditions of sale, which are available on request.

Any brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.

#### **HEADQUARTERS OPERATIONS**

DYNEX SEMICONDUCTOR LIMITED
Doddington Road, Lincoln, Lincolnshire. LN6 3LF

United Kingdom.

Phone: +44 (0) 1522 500500

Web: <a href="http://www.dynexsemi.com">http://www.dynexsemi.com</a>

#### **CUSTOMER SERVICE**

Phone: +44 (0) 1522 502753 / 502901

e-mail: powersolutions@dynexsemi.com

© Dynex Semiconductor Ltd. Technical Documentation – Not for resale.

www.dynexsemi.com 7/7